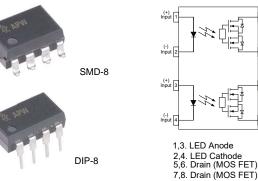
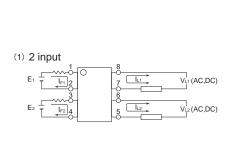
#### 2 Form A APW225G1EH SMD-8 DIP-8 Load Voltage:100V Load Current:1100mA

Parameter	Symbol	Rating	Units	
Load Voltage	VL	100	V	
Load Current	١L	1.1	А	
On-Resistance	Ron	0.27	Ω	
I/O Breakdown Voltage	V/ıo	5000	Vrms	

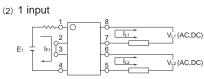
APSEMI





TSCA UPDATE

E534710



#### **APSEMI PhotoRelays**

®

APSEMI Photorelays are the most reliable, technically advanced logic-to-power interface devices. Their basic function is to take a low current signal from a microprocessor to control the switching of both AC and DC loads, while providing an isolation barrier between logic and power. While this function is common to all relays, Photorelays provide distinct advantages over their mechanical counterparts including:

(-/+)

- Long life (No limit on mechanical and electrical
- lifetime)Bounce-free switching
- Higher speed and high frequency switching
- Higher sensitivity (less power consumption)

- No have voltaic arc, bounce, and noise More
- resistant to vibration and impact AC or DC load
- switching
- Small package size

Immunity to EMI or RFI

#### Applications

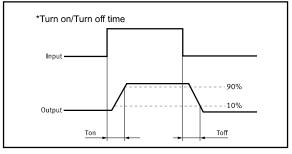
These advantages make APSEI Photorelays the ideal choice for:

- Telecom/Datacom switching .
- Multiplexers •
- Meter reading systems
- Data acquisition
- Medical equipment
- Battery monitoring •
- I/O Sub-Systems •

- Robotics
- Aerospace
- Home/Safety security systems
- Process Control
- **Energy Management** Reed Relay EMR Replacement •
- Programmable Controllers

#### TPYES

Output Rating		Baakaga	Part No.	Packing Quantity	
Category Load Voltage Load Current	Package	Fall NO.			
AC/DC 100V	4.4.4	DIP-8	APW225G1E	50pcs /tube	
	1000	1.1A	SMD-8	APW225G1EH	1000pcs /reel



# Absolute Maximum Ratings (Ta = 25°C)

	Item	Symbol	Value	Units	Note
Continuous LED Current		F	50	mA	
Input	Peak LED Current	<b>I</b> FP	1000	mA	f=100Hz, duty=1%
	LED Reverse Voltage	VR	5	V	
	Input Power Dissipation	Pin	75	mW	
	Load Voltage	VL	100	V(AC peak or DC)	
	Load Current	L	1.1	А	
Output	Peak Load Current	Peak	2.5	А	100ms(1 pulse)
	Output Power Dissipation	Pout	450	mW	
Total Powe	er Dissipation	P⊤	500	mW	
I/O Breakd	lown Voltage	Vi/o	5000	Vrms	RH=60%, 1min
Operating	Temperature	Topr	-40 to 85	°C	
Storage Te	emperature	Tstg	-40 to 100	°C	
Pin Solder	ing Temperature	Tsol	260	°C	10 sec max.

## Electrical Characteristics (Ta = 25°C)

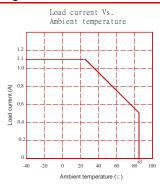
	Item	Symbol	MIN.	TYP.	MAX.	Units	Conditions	
	LED Forward Voltage	VF		1.2	1.4	V	l⊧=10mA	
	Operation LED Current	Fon		0.5	3.0	mA		
Input	Recovery LED Current	Foff		0.35	0.5	mA		
	Recovery LED Voltage	VFoff	0.5			V		
Output	On-Resistance	Ron		0.27	0.7	Ω	I⊧=5mA,I∟=100mA, Time to flow is within 1 sec.	
	Off-State Leakage Current	Leak	0.01	0.02	0.1	uA	V₋=Rating	
	Output Capacitance	Cout		90		pF	V∟=0, f=1MHz	
Transmis	Turn-On Time	Ton		1.5	5.0	ms	l⊧=5mA, l∟=100mA,	
sion	Turn-Off Time	Toff		0.05	2.0	ms		
Ocumbral	I/O Isolation Resistance	Ri⁄o	10 <sup>10</sup>			Ω	DC500V	
Coupled	I/O Capacitance	Ci/o		0.8	1.5	pF	f=1MHz	

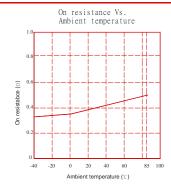
Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value): IF ≥5mA and ≤30mA

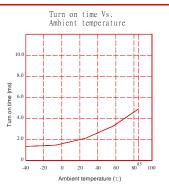
# ® APSEMI

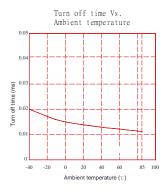
# 2 Form A APW225G1EH SMD-8 DIP-8 Load Voltage:60V Load Current:1100mA

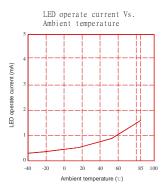
## **Engineering Data**





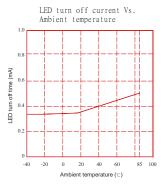




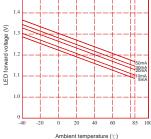


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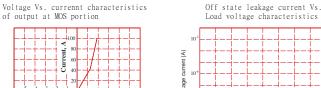
Voltage, V

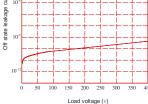


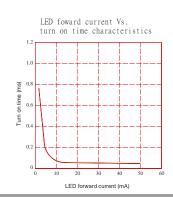
LED forward voltage Vs. Ambient temperature 1.5



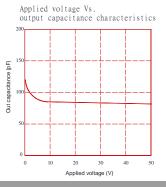
Current,







LED foward current Vs. turn off time characteristics (sm off time ŝ 40 20 30 50 60 LED forward current (mA)

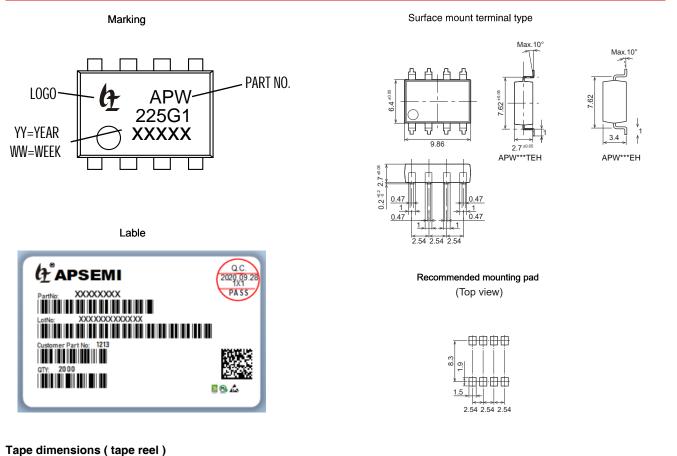


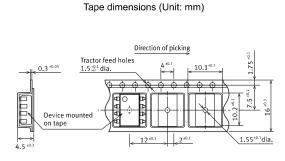
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# Dimensions and SMD-8 Package Unit: mm

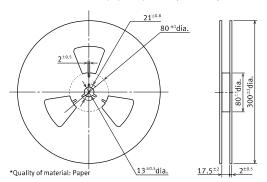
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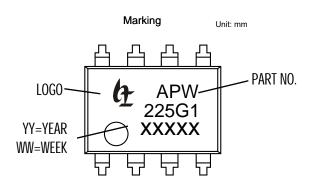


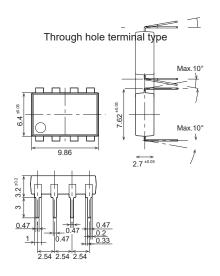
Dimensions of paper tape reel (Unit: mm)





## Dimensions and DIP-8 Package

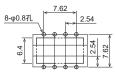




Lable

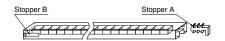


PC board pattern (Bottom view)



# DIP Tape dimensions Unit : mm

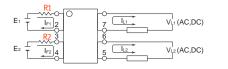
Devices are packaged in a tube so that pin No. 1 is on the stopper B side. Observe correct orientation when mounting them on PC boards.





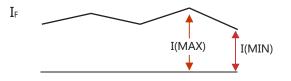
## Using Methods

Examples of resistance value to control LED forward current (IF=5mA)



E1 E2	R1 R2(Approx)
3.3V	300 Ω
5.0V	600 Ω
12V	1.9KΩ
24V	4.1K Ω

LED forward current must be more than 5mA , at I(MIN) ,and less than 30mA , at I(MAX).



#### **Recommended Operating Conditions**

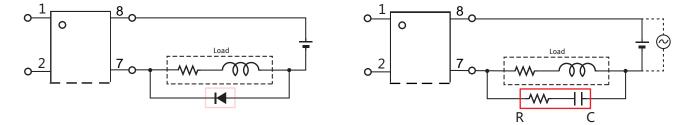
Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value):

Characteristic	Symbol	Min	Тур.	Max	Unit
Forward current	١ <sub>F</sub>	5.0	7.0	30	mA

#### **Protection Circuit**

Clamp diode is connected in parallel with the load. Absorb capacity with external diode.

CR Snubber is connected in parallel with the load. Absorb capacity with buffer capacity.



When adding diodes, buffer circuits (C-R), and other protections, they need to be installed near the MOS RELAY to be effective. Adding protection elements may result in a slow reset time, so adjust them according to the actual situation before use.

Note: When developing designs using this product, perform the expected performance of the equipment under the operating conditions recommended by the guidelines in this document. Continuous use under heavy loads (including, but not limited to, the application of high temperatures/current/voltage and significant changes in temperature, etc.) may result in deterioration of the reliability of this product.

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